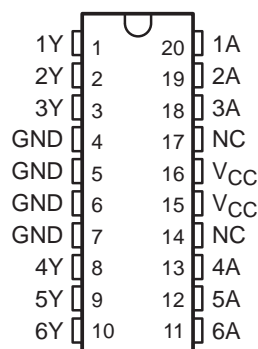


# 74ACT11004 HEX INVERTER

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- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes PCB Layout
- Center-Pin  $V_{CC}$  and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1- $\mu$ m Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages and Standard Plastic (N) 300-mil DIPs

DB, DW, N, OR PW PACKAGE  
(TOP VIEW)



NC – No internal connection

## description

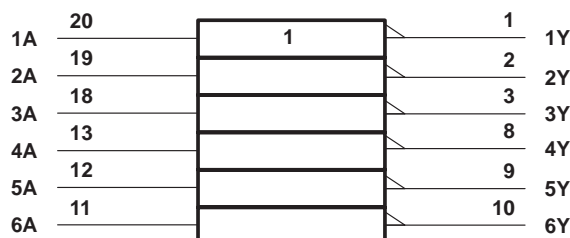
This device contains six independent inverters. It performs the Boolean function  $Y = \bar{A}$ .

The 74ACT11004 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

FUNCTION TABLE  
(each inverter)

INPUT A	OUTPUT Y
H	L
L	H

## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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 **TEXAS  
INSTRUMENTS**

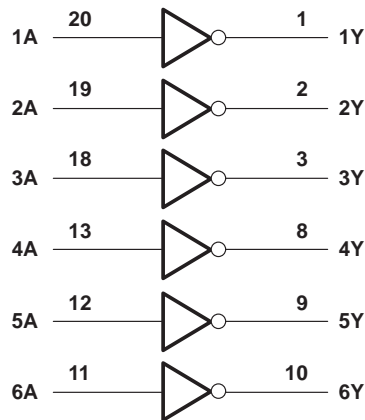
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# 74ACT11004 HEX INVERTER

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## logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$	.....	-0.5 V to 7 V
Input voltage range, $V_I$ (see Note 1)	.....	-0.5 V to $V_{CC} + 0.5$ V
Output voltage range, $V_O$ (see Note 1)	.....	-0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	.....	$\pm 20$ mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ )	.....	$\pm 50$ mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	.....	$\pm 50$ mA
Continuous current through $V_{CC}$ or GND	.....	$\pm 150$ mA
Package thermal impedance, $\theta_{JA}$ (see Note 2):		
DB package	.....	115°C/W
DW package	.....	97°C/W
N package	.....	67°C/W
PW package	.....	128°C/W
Storage temperature range, $T_{stg}$	.....	-65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.  
2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

## recommended operating conditions

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	4.5	5.5	V
$V_{IH}$	High-level input voltage	2		V
$V_{IL}$	Low-level input voltage		0.8	V
$V_I$	Input voltage	0	$V_{CC}$	V
$V_O$	Output voltage	0	$V_{CC}$	V
$I_{OH}$	High-level output current		-24	mA
$I_{OL}$	Low-level output current		24	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
$T_A$	Operating free-air temperature	-40	85	°C



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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
V <sub>OH</sub>	I <sub>OH</sub> = -50 μA	4.5 V	4.4			4.4		V
		5.5 V	5.4			5.4		
	I <sub>OH</sub> = -24 mA	4.5 V	3.94			3.8		
		5.5 V	4.94			4.8		
	I <sub>OH</sub> = -75 mA <sup>†</sup>	5.5 V				3.85		
V <sub>OL</sub>	I <sub>OL</sub> = 50 μA	4.5 V	0.1			0.1		V
		5.5 V	0.1			0.1		
	I <sub>OL</sub> = 24 mA	4.5 V	0.36			0.44		
		5.5 V	0.36			0.44		
	I <sub>OL</sub> = 75 mA <sup>†</sup>	5.5 V				1.65		
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5 V	±0.1			±1		μA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	5.5 V	4			40		μA
ΔI <sub>CC</sub> <sup>‡</sup>	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V	0.9			1		mA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V	3.5					pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ns.

<sup>‡</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V<sub>CC</sub>.

**switching characteristics over recommended ranges of supply voltage and free-air temperature (unless otherwise noted) (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T <sub>A</sub> = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
t <sub>PLH</sub>	A	Y	1.5	5.3	9	1.5	9.7	ns
t <sub>PHL</sub>			1.5	6.4	8.7	1.5	9.6	

**operating characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C**

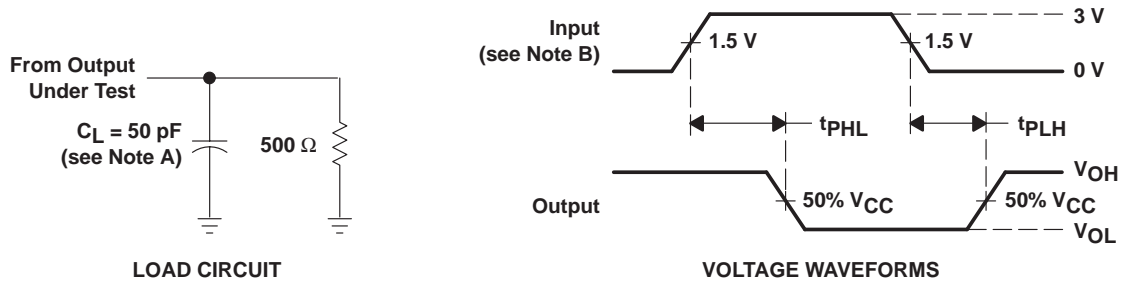
PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance per inverter	C <sub>L</sub> = 50 pF, f = 1 MHz	32	pF



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## PARAMETER MEASUREMENT INFORMATION



- NOTES: A.  $C_L$  includes probe and jig capacitance.  
B. Input pulses are supplied by generators having the following characteristics:  $PRR \leq 1 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r = 3 \text{ ns}$ ,  $t_f = 3 \text{ ns}$ .  
C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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